TO. :

NO. :

APPROVAL SHEET

MULTILAYER CERAMIC CAPACITOR

Automotive Grade

(AEC-Q200 Qualified)

Approved by customer : (signing or stamping here)

SAMWHA CAPACITOR CO., LTD.		
Prepared by	Checked by	Approved by

2020. 04. 23.

SAMWHA CAPACITOR CO., LTD.

Address : 124, BUK-RI, NAMSA-MYUN YOUNGIN-SI, KYUNGKI-DO, KOREA

Contact : TEL 82-31-332-6441 , FAX 82-31-332-7661

Home page : www.samwha.com

< SPECIFICATION SUMMARY >

SAMWHA Part no.	CQ1005X7R223K250NR		
Type	MLCC for Automotive Application		
Items	Specification	Unit	Test Conditions
Capacitance	22	nF	Testing Frequency : 1 ±0.1 kHz Testing Voltage : 1 ±0.2 Vrms Should be measured at 25℃.
Capacitance Tolerance	± 10	%	
Dissipation Factor	Max. 3	%	
Insulation Resistance	Min. 10,000	MΩ	Should be measured with a DC voltage not exceeding rated voltage at 25℃ for 2 minutes of charging.
Chip Size	1.00 ±0.05	L (㎜)	Capacitance Tolerance Code ------- page 1/9 Chip size ---------- page 2/9 Characteristics & Test Method ----- page 3/9~6/9
	0.50 ±0.05	W (㎜)	
	0.50 ±0.05	T (㎜)	

Contents

1. General Code

(1) Type Designation

CQ	1005	X7R	223	K	250	N	R	_
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

1) Multilayer Ceramic Capacitor (Automotive Grade)

2) Size Code :

This is expressed in tens of a millimeter.
The first two digits are the length, The last two digits are width.

3) Temperature Coefficient Code

Classification	Code	Temperature Range	Capacitance Tolerance
Class Ⅰ	C0G	-55 to +125℃	±30 ppm/℃
Class Ⅱ	X7R	-55 to +125℃	±15%
	X7S	-55 to +125℃	±22%
	X7T	-55 to +125℃	+22% ~ -33%
	X6S	-55 to +105℃	±22%

4) Capacitance Code(Pico farads) :
The nominal Capacitance Value in pF is expressed by three digit numbers.
The first two digits represents significant figures and the last digit denotes the number of zero
ex) 104 = 100000 pF
R denotes decimal
8R2 = 8.2 pF

5) Capacitance Tolerance Code

Code	Tolerance
B	± 0.1 pF
C	± 0.25 pF
D	± 0.5 pF
F	± 1.0 %

Code	Tolerance
G	± 2.0 %
J	± 5 %
K	± 10 %
M	± 20 %

6) Voltage Code

Code	6R3	100	160	250	350	500	101	201	251	501	631	102	202	302
Rated Voltage	DC 6.3V	DC 10V	DC 16V	DC 25V	DC 35V	DC 50V	DC 100V	DC 200V	DC 250V	DC 500V	DC 630V	DC 1KV	DC 2KV	DC 3KV

7) Termination Code
N : Nickel-Tin Plate
A : Nickel-Tin Plate -> Soft Termination Type

8) Packing Code
R : 7“ Reel Type, L : 13“ Reel Type, B : Bulk Type

9) Thickness option

Thickness (mm)		Code	Thickness (mm)		Code
t	Tolerance(±)		t	Tolerance(±)	
0.50	0.05	Blank	1.35	0.20	H
0.60	0.10	A	1.60	0.20	I
0.80	0.10	B	1.80	0.20	J
0.85	0.15	B	2.00	0.25	K
1.00	0.15	E	2.50	0.25	L
1.10	0.15	E	2.80	0.30	M
1.15	0.15	E	3.20	0.30	N
1.25	0.15	E	5.00	0.40	O
1.30	0.20	E			

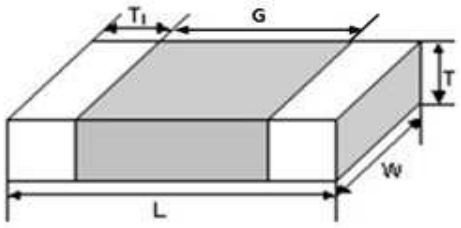
*3216 Size ≥2.2㎌ 100V ⇒ T : Tol±0.30

2. Temperature Characteristics

See Page 6/9 (No.21)

3. Constructions and Dimensions

(1) Dimensions

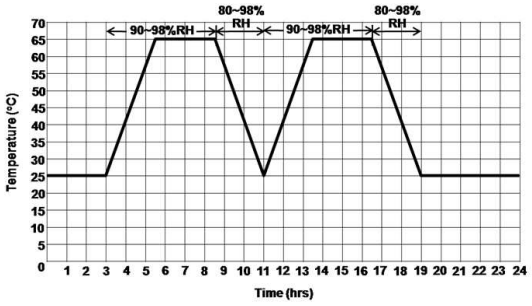


Size Code	EIA Code	Dimension					
		Length		Width		T1(min.)	G(min.)
		L	Tol(±)	W	Tol(±)		
1005	0402	1.00	0.05	0.50	0.05	0.05	0.30
1608	0603	1.60	0.15	0.80	0.10	0.10	0.50
2012	0805	2.00	0.20	1.25	0.15	0.10	0.65
3216	1206	3.20	0.30	1.60	0.20	0.15	1.00
3225	1210	3.20	0.40	2.50	0.25	0.15	1.05
4520	1808	4.50	0.40	2.00	0.25	0.20	1.50
4532	1812	4.50	0.40	3.20	0.30	0.20	1.50
5750	2220	5.70	0.50	5.00	0.40	0.30	1.85

*3216 Size ≥2.2㎌ 100V ⇒ L, W : Tol±0.30 (Unit : ㎜)

(2) Construction of Termination

Specifications and Test Methods (For Automotive Applications)

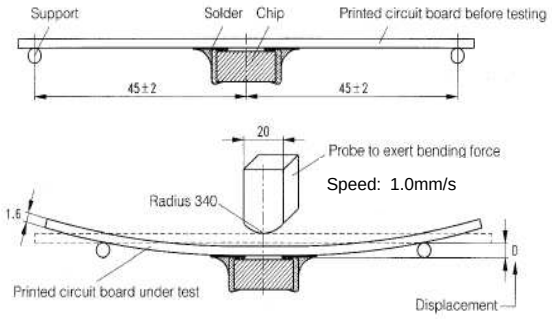
No.	AEC-Q200 Test Item		Specification Class Ⅰ	Specification Class Ⅱ	Test Methods and Conditions
1	Pre-and Post-Stress Electrical Test		-		
2	High Temperature Exposure (Storage)	Appearance	No defects which may affect performance		Temperature : Max. operating temperature±3℃ Maintenance Time : 1000+48/-0 hrs Let sit for 24±2 hours at room temperature, then measure.
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10.0% (*Within ±12.5%)	
		Q/D.F.	30pF min.: Q≧1000 30pF max.: Q≧400+20×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max. 10V: 0.075 max. *0.2 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		
3	Temperature Cycle	Appearance	No defects which may affect performance		Perform the 1000 cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room temperature, then measure. Step 1: -55+0/-3, 15±3 min Step 2: 25±2, 1 min Step 3: 125+3/-0, 15±3 min Step 4: 25±2, 1 min Initial measurement Perform the initial measurement according to Note 1 for Class II.
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10.0%	
		Q/D.F.	30pF min.:Q≧1000 30pF max.:Q≧400+20×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max. 10V: 0.075 max. *0.2 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		
4	Destructive Physical Analysis		No defects or abnormalities		Per EIA-469
5	Moisture Resistance	Appearance	No defects which may affect performance		Temperature : 25~65℃, Humidity : 80~98% Cycle Time : 24 hrs/cycle, 10 cycles Let sit for 24±2 hours at room temperature, then measure. 
		Capacitance Change	Within ±3.0% or±0.30pF (Whichever is larger)	Within ±12.5%	
		Q/D.F.	30pF min.: Q≧350 10pF min. and 30pF max.: Q≧275+5/2×C 10pF max.: Q≧200+10×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max. 10V: 0.075 max. *0.2 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		
6	Biased Humidity	Appearance	No defects which may affect performance		Temperature : 85±3℃ Humidity : 80~85% Applied Voltage : Rated Voltage and 1.3+0.2/-0V Maintenance Time : 1000+48/-0 hrs Let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Capacitance Change	Within ±3.0% or ±0.30pF (Whichever is larger)	Within ±12.5%	
		Q/D.F.	30pF min.: Q≧200 30pF max.: Q≧100+10/3×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max. 10V: 0.075 max. *0.2 max.	
		I.R.	More than 1,000MΩ or 50Ω·F (*5Ω·F) (Whichever is smaller)		
7	Operational Life	Appearance	No defects which may affect performance		Temperature : Max. operating temperature±3℃ Applied Voltage : Rated Voltage × 200% (*150%) Maintenance Time : 1000+48/-0 hrs Let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. Initial Measurement for Class II Applied 200% of the rated voltage for one hour at 125±3℃. Remove and let sit for 24±2 hours at room temperature, then measure.
		Capacitance Change	Within ±3.0% or ±0.30pF (Whichever is larger)	Within ±12.5%	
		Q/D.F.	30pF min.:Q≧350 10pF min. and 30pF max.: Q≧275+5/2×C 10pF max.: Q≧200+10×C C: Nominal Capacitance (pF)	Rated Voltage 16V min.: 0.05 max. 10V: 0.075 max. *0.2 max.	
		I.R.	More than 1,000MΩ or 50Ω·F (*5Ω·F) (Whichever is smaller)		

Specifications and Test Methods (For Automotive Application)

No.	AEC-Q200 Test Item		Specification Class Ⅰ	Specification Class Ⅱ	Test Methods and Conditions
8	External Visual		No defects or abnormalities		Visual inspection
9	Physical Dimension		Within the specified dimensions		Using calipers
10	Resistance to Solvents	Appearance	No defects which may affect performance		Per MIL-STD-202 Method 215
		Capacitance Change	Within the specified tolerance		
		Q/D.F.	30pF min.: Q≧1000 30pF max.: Q≧400+20×C C: Nominal Capacitance (pF)	Rated Voltage 50V: 0.025 max. 25V: 0.03 max. 16V: 0.035 max. 10V: 0.05 max. *0.125 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		
11	Mechanical Shock	Appearance	No defects which may affect performance		Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks) Test Pulse Wave form : Half-sine Duration : 0.5ms Peak value : 1,500G Velocity change : 4.7m/s
		Capacitance Change	Within the specified tolerance		
		Q/D.F.	30pF min.:Q≧1000 30pF max.:Q≧400+20×C C: Nominal Capacitance (pF)	Rated Voltage 50V: 0.025 max. 25V: 0.03 max. 16V: 0.035 max. 10V: 0.05 max. *0.125 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		
12	Vibration	Appearance	No defects or abnormalities		The specimens should be subjected to a simple harmonic motion having a total amplitude of 1.5mm. The entire frequency range of 10 to 2,000 Hz and return to 10 Hz should be traversed in 20 minutes. This cycle should be performed 12 times in each of three mutually perpendicular directions (total of 36 times).
		Capacitance Change	Within the specified tolerance		
		Q/D.F.	30pF min.:Q≧1000 30pF max.:Q≧400+20×C C: Nominal Capacitance (pF)	Rated Voltage 50V: 0.025 max. 25V: 0.03 max. 16V: 0.035 max. 10V: 0.05 max. *0.125 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		
13	Resistance to Soldering Heat	Appearance	No defects which may affect performance		Temperature (Eutectic solder solution) : 260±5℃ Dipping Time : 10±1s Let sit for 24±2 hours at room temperature, then measure. Initial measurement Perform the initial measurement according to Note 1 for Class II.
		Capacitance Change	Within the specified tolerance		
		Q/D.F.	30pF min.:Q≧1000 30pF max.:Q≧400+20×C C: Nominal Capacitance (pF)	Rated Voltage 50V: 0.025 max. 25V: 0.03 max. 16V: 0.035 max. 10V: 0.05 max. *0.125 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		
14	Thermal Shock	Appearance	No defects which may affect performance		Perform the 300 cycles according to the two heat treatments listed in the following table. Transfer Time : 20sec. max. Let sit for 24±2 hours at room temperature, then measure. Initial measurement Perform the initial measurement according to Note 1 for Class II.
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±15.0%	
		Q/D.F.	30pF min.:Q≧1000 30pF max.:Q≧400+20×C C: Nominal Capacitance (pF)	Rated Voltage 50V: 0.025 max. 25V: 0.03 max. 16V: 0.035 max. 10V: 0.05 max. *0.125 max.	
		I.R.	More than 10,000MΩ or 500Ω·F (*50Ω·F) (Whichever is smaller)		

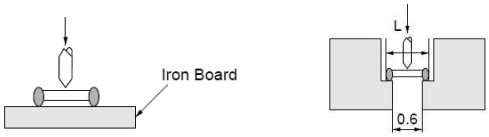
Step	1	2
Temp.(℃)	-55+0/-3	125+3/-0
Time(min.)	15±3	15±3

Specifications and Test Methods (For Automotive Application)

<table>
<tr><th rowspan="2">No.</th><th rowspan="2" colspan="2">AEC-Q200
Test Item</th><th colspan="2">Specification</th><th rowspan="2">Test Methods and Conditions</th></tr>
<tr><th>Class Ⅰ</th><th>Class Ⅱ</th></tr>
<tr><td rowspan="4">15</td><td rowspan="4">ESD</td><td>Appearance</td><td colspan="2">No defects which may affect performance</td><td rowspan="4">Per AEC-Q200-002</td></tr>
<tr><td>Capacitance Change</td><td colspan="2">Within the specified tolerance</td></tr>
<tr><td>Q/D.F.</td><td>30pF min.:Q≧1000
30pF max.:Q≧400+20×C
C: Nominal Capacitance (pF)</td><td>Rated Voltage 50V: 0.025 max.
25V: 0.03 max.
16V: 0.035 max.
10V: 0.05 max.
*0.125 max.</td></tr>
<tr><td>I.R.</td><td colspan="2">More than 10,000MΩ or 500Ω·F (*50Ω·F)
(Whichever is smaller)</td></tr>
<tr><td>16</td><td colspan="2">Solderability</td><td colspan="2">95% of the terminations is to be soldered evenly and continuously.</td><td>(a) Preheat at 155℃ for 4 hours, and then immerse the capacitor in a solution of ethanol and rosin. Immerse in eutectic solder solution for 5+0/-0.5 seconds at 235±5℃.
(b) Steam aging for 8 hours, and then immerse the capacitor in a solution of ethanol and rosin. Immerse in eutectic solder solution for 5+0/-0.5 seconds at 235±5℃.
(c) Steam aging for 8 hours, and then immerse the capacitor in a solution of ethanol and rosin. Immerse in eutectic solder solution for 120±5 seconds at 260±5℃.</td></tr>
<tr><td rowspan="5">17</td><td rowspan="5">Electrical Characteriza-tion</td><td>Appearance</td><td colspan="2">No defects or abnormalities</td><td rowspan="3">The capacitance/Q/D.F. should be measured at 25℃ at the frequency and voltage shown in the table.
<table><tr><th>Class</th><th>Capacitance (C)</th><th>Frequency</th><th>Voltage</th></tr><tr><td rowspan="2">Class Ⅰ</td><td>C<1000pF</td><td>1±0.1MHz</td><td>0.5~5Vrms</td></tr><tr><td>C≧1000pF</td><td>1±0.1kHz</td><td>1±0.2Vrms</td></tr><tr><td rowspan="2">Class Ⅱ</td><td>C≦10μF</td><td>1±0.1kHz</td><td>0.5~1.0Vrms</td></tr><tr><td>C>10μF</td><td>120±24Hz</td><td>0.5±0.1Vrms</td></tr></table>· Initial measurement
Perform the initial measurement according to Note1 for Class Ⅱ
· Measurement after test
Take it out and set it for 24±2 hours (Class Ⅱ) then measure</td></tr>
<tr><td>Capacitance Change</td><td colspan="2">Within the specified tolerance</td></tr>
<tr><td>Q/D.F.</td><td>30pF min.:Q≧1000
30pF max.:Q≧400+20×C
C: Nominal Capacitance (pF)</td><td>Rated Voltage 50V: 0.025 max.
25V: 0.03 max.
16V: 0.035 max.
10V: 0.05 max.
*0.125 max.</td></tr>
<tr><td>I.R. at 25℃</td><td>More than 100,000MΩ or 1,000Ω·F
(Whichever is smaller)</td><td>More than 10,000MΩ 500Ω·F
(*50Ω·F) (Whichever is smaller)</td><td rowspan="2">Should be measured with a DC voltage not exceeding rated voltage at 25℃ and 125℃ for 2 minutes of charging.</td></tr>
<tr><td>I.R. at 125℃</td><td>More than 10,000MΩ or 100Ω·F
(Whichever is smaller)</td><td>More than 1,000MΩ or 10Ω·F
(*1Ω·F) (Whichever is smaller)</td></tr>
<tr><td></td><td>Dielectric Strength</td><td colspan="2">No dielectric breakdown or mechanical breakdown</td><td>Applied 250% of the rated voltage for 1~5 seconds
The charge/discharge current is less than 50mA.</td></tr>
<tr><td rowspan="2">18</td><td rowspan="2">Board Flex</td><td>Appearance</td><td colspan="2">No defects which may affect performance</td><td rowspan="2">Apply a force in the direction shown in the following figure for 60±5 seconds.
 

Flexure for Class Ⅰ: 3mm max.
for Class Ⅱ: 2mm max.</td></tr>
<tr><td>Capacitance Change</td><td>Within ±5.0% or ±0.5pF
(Whichever is larger)</td><td>Within the specified tolerance</td></tr>
<tr><td rowspan="2">19</td><td rowspan="2">Terminal Strength</td><td>Appearance</td><td colspan="2">No defects which may affect performance</td><td rowspan="2">Apply 18N[1] force in parallel with the test jig for 60±1 seconds.
[1]10N for 1608(EIA:0603) size
2N for 1005(EIA:0402) size</td></tr>
<tr><td>Capacitance Change</td><td>Within ±5.0% or ±0.5pF
(Whichever is larger)</td><td>Within the specified tolerance</td></tr>
</table>

Specifications and Test Methods (For Automotive Application)

<table>
<tr><th rowspan="2">No.</th><th rowspan="2" colspan="2">AEC-Q200
Test Item</th><th colspan="2">Specification</th><th rowspan="2">Test Methods and Conditions</th></tr>
<tr><th>Class Ⅰ</th><th>Class Ⅱ</th></tr>
<tr><td>20</td><td colspan="2">Beam Load Test</td><td colspan="2">The chip endure following force.
<table><tr><th>Chip Length</th><th>Thickness (T)</th><th>Force</th></tr><tr><td rowspan="2">2.5mm max.</td><td>T≤0.5mm</td><td>8N</td></tr><tr><td>T>0.5mm</td><td>20N</td></tr><tr><td rowspan="2">3.2mm min.</td><td>T<1.25mm</td><td>15N</td></tr><tr><td>T≥1.25</td><td>54.5N</td></tr></table></td><td>Apply a force as shown in the following figure.
(i) Chip Length : 2.5mm max. (ii) Chip Length : 3.2mm min.
Beam Speed : 0.5mm/s Beam Speed : 2.5mm/s
  </td></tr>
<tr><td rowspan="3">21</td><td rowspan="3">Capacitance Temperature Characteris-tics</td><td>Capacitance Change</td><td></td><td>X7R : Within ±15%
X7S : Within ±22%
X6S : Within ±22%
X7T : Within +22% ~ -33%</td><td rowspan="3">(i) Class I
The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance should be within the specified tolerance for the temperature coefficient. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in steps 1, 3 and 5 by the capacitance value in step 3.
<table><tr><td>Step</td><td>1</td><td>2</td><td>3</td><td>4</td><td>5</td></tr><tr><td>Temp.(℃)</td><td>25±2</td><td>-55±3</td><td>25±2</td><td>125±3</td><td>25±2</td></tr></table>
(ii) Class II
The ranges of capacitance change compared with the 25℃ value over the temperature range from -55℃ to 125℃.
Initial measurement
Perform the initial measurement according to Note 1 for Class II.</td></tr>
<tr><td>Temperature Coefficient</td><td>0±30 ppm/℃</td><td></td></tr>
<tr><td>Capacitance Drift</td><td>Within ±0.2% or ±0.05pF
(Whichever is larger)</td><td></td></tr>
</table>

In the case of "*" is specifications for "Thin Layer Large Capacitance Type"

Note 1. Initial Measurement for Class II
Perform a heat treatment at 150+0/-10℃ for one hour, and then let sit for 24±2 hours at room temperature, then measure.

Packing

(1) Bulk Packing

① 1000 pcs per polybag

② 5 polybags per inner box

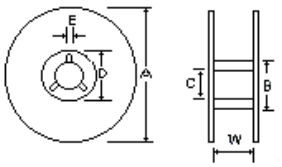
③ 10 inner boxes per out box

(2) Reel Packing

① 8~10 reels per inner box

② 6 inner boxes per out box

(3) Reel Dimensions



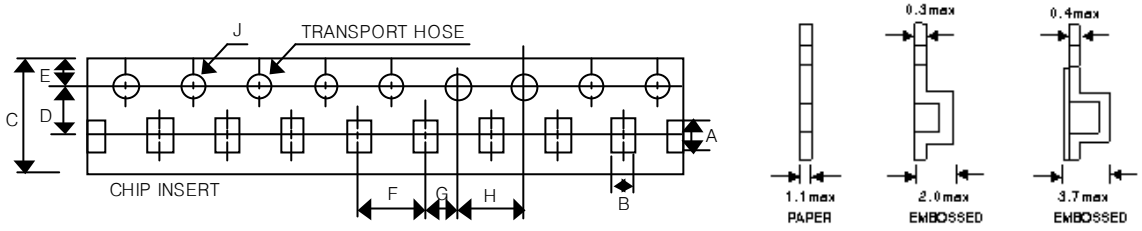
(Unit : mm)

Mark	Size Code	EIA Code	A	B	C	D	E	W
7 " Reel	1005~3225	0402~1210	Φ178±2	Φ50Min	Φ13±0.5	Φ21±0.8	2±0.5	10±1.5
	4520~4532	1808~1812	Φ180+0,−3	Φ60−0,+1	Φ13±0.2	Φ57−0+1	3±0.2	13±0.5
13 " Reel	1005~3225	0402~1210	Φ330±2	Φ70Min	Φ13±0.5	Φ21±0.8	2±0.5	10±1.5

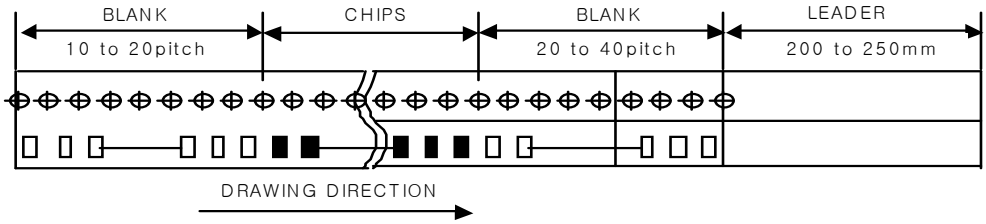
(4) Number of Package

Size Code	EIA Code	7"	13"
		Quantity(pcs)/Reel	Quantity(pcs)/Reel
1005	0402	10,000	50,000
1608	0603	4,000	15,000
2012	0805	3,000 ~ 4,000	8,000 ~ 15,000
3216	1206	2,000 ~ 4,000	6,000 ~ 10,000
3225	1210	1,000 ~ 3,000	4,000 ~ 10,000
4520	1808	1,500 ~ 3,000	-
4532	1812	500 ~ 1,000	1,500 ~ 5,000

(5) Tape Dimensions



Size Code	EIA Code	A	B	C	D	E	F	G	H	J
1005	0402	1.15±0.1	0.65±0.1	8.0±0.3	3.5±0.05	1.75±0.1	2.0±0.05	2.0±0.1	4.0±0.1	1.5±0.1
1608	0603	1.9±0.2	1.10±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
2012	0805	2.4±0.2	1.65±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
3216	1206	3.6±0.2	2.00±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
3225	1210	3.6±0.2	2.80±0.2	8.0±0.3	3.5±0.05	1.75±0.1	4.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
4520	1808	4.8±0.2	2.3±0.2	12.0±0.3	5.5±0.1	1.75±0.1	4.0±0.1 8.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1
4532	1812	4.9±0.2	3.6±0.2	12.0±0.3	5.5±0.1	1.75±0.1	8.0±0.1	2.0±0.1	4.0±0.1	1.5±0.1



Caution

▶ Storage Condition

When solderability is considered, capacitor are recommended to be used in 12 months.

(1) Temperature: 25℃ ± 10℃

(2) Relative Humidity: Below 70% RH

▶ The Regulation of Environmental Pollution Materials

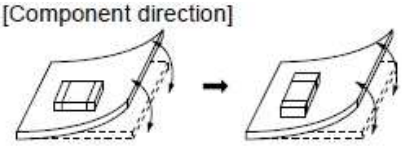
Never use materials mentioned below in MLCC products regulated this document.

Pb, Cd, Hg, Cr^{+6}, PBB(Polybrominated biphenyl), PBDE(Polybrominated diphenyl ethers), asbestos

▶ Mounting Position

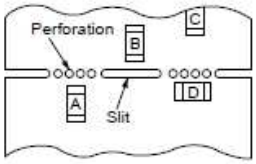
Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board.

[Component direction]



Locate chip horizontal to the direction in which stress acts.

[Chip Mounting Close to Board Separation Point]



Chip arrangement
Worst A-C- (B, D)
Best

▶ Reflow Soldering

1. The sudden temperature change easily causes mechanical damages to ceramic components. Therefore, the preheating procedures should be required for the soldering of ceramic components.

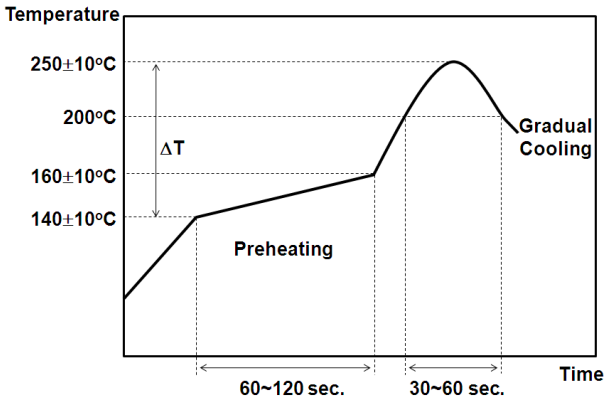
2. Please refer to the recommended soldering profiles as shown in figures, and keep the temperature difference(△T) within the range recommended in Table 1.

Table 1

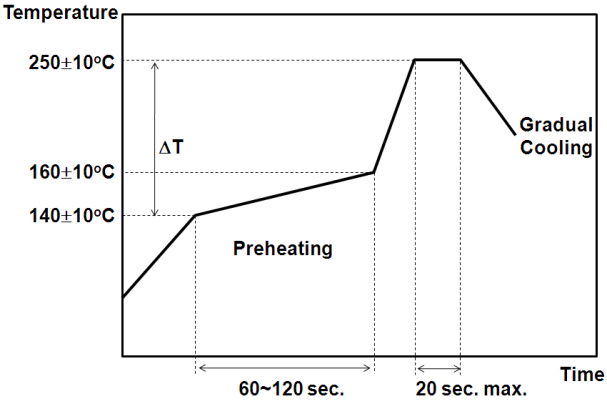
Size code (EIA Code)	Temperature Difference
1005~3216 (0402~1206)	△T≤190℃
3225 (1210)	△T≤130℃

Recommended Reflow Soldering Profile for Lead Free Solder

Infrared Reflow



Vapor Reflow



Note

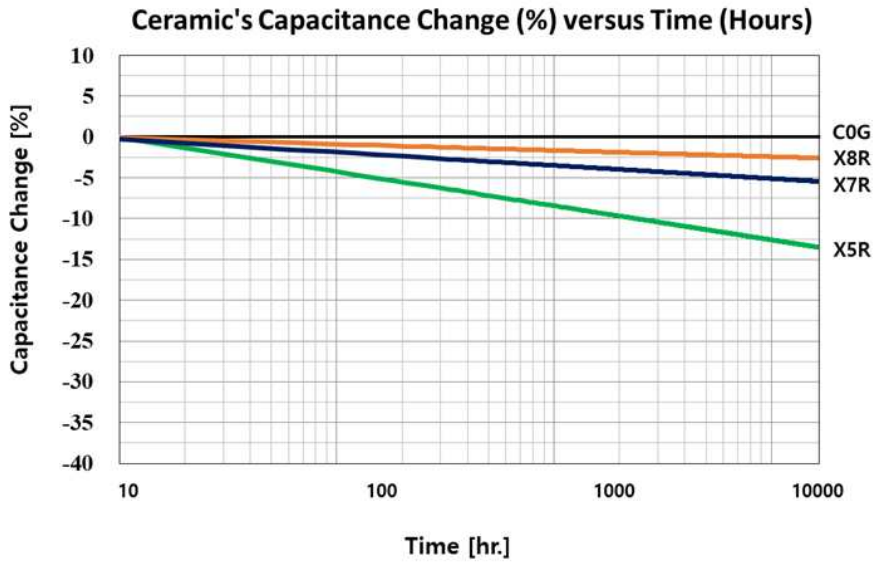
▶ 'Aging'/'De-aging' behavior of high dielectric constant type MLCCs
(Typically represented by X7R temperature characteristic of which main composition is $BaTiO_3$)

'Aging' / 'De-aging' Behavior of high dielectric MLCCs Please note that high dielectric type dielectric ceramic capacitors have a "normal" 'aging' behavior / characteristic, that is; their capacitance value decreases with time from its value when it was first manufactured. From that date, the capacitance value begins to decrease at a logarithmic rate defined by:

$C_t = C_{24} (1 - k \log_{10} t)$

where,

C_t : Capacitance value, t hours after the start of 'aging'
C_{24} : Capacitance value, 24 hours after its manufacture
k : Aging constant (capacitance decrease per decade-hour)
t : time, in hours, from the start of 'aging'



The capacitance value can be restored (also known as 'de-aged') by exposing the component to elevated temperatures approaching its curie temperature (approximately 120℃). This 'de-aging' can occur during the component's solder-assembly onto the PCB, during life or temperature cycle testing, or by baking at 150℃ for about 1 hour.